NSN 5961-00-922-2945

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View Online at https://aerobasegroup.com/nsn/5961-00-922-2945 **Inclosure Material:** Glass **Overall Length:** 0.450 inches **Terminal Length:** 0.900 inches **Overall Height:** 0.200 inches **Overall Width:** 0.300 inches **Internal Configuration:** Junction contact all semiconductor device diode **Electrode Internally-electrically Connected To Case:** Collector **Internal Junction Configuration:** Pn all semiconductor device diode **Component Function Relationship:** Matched **Component Name And Quantity:** 2 semiconductor device diode **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 75.0 reverse voltage, peak all semiconductor device diode **Current Rating Per Characteristic:** 75.00 milliamperes forward current, average absolute all semiconductor device diode **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-collector absolute all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

No

Demilitarization:

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